

ARPES Investigation of Pseudogap in Bi2212

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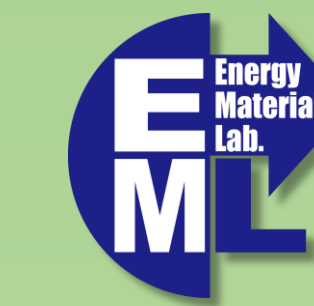
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Cuprate superconductors are characterized by high critical temperatures exceeding liquid nitrogen temperature (77K), giving them a strong potential for industrial applications. However, a dip in the density of electronic states near the Fermi energy, named the pseudogap, was found to reduce the number of electrons contributing to the superconducting state, and, as a result, decrease the critical temperature. A better understanding of the pseudogap and superconducting states may allow the critical temperature of these superconductors to be further increased. The current study employed Angle-Resolved Photoemission Spectroscopy (ARPES) to characterize the superconducting gap and pseudogap of $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (Bi2212), a high critical temperature cuprate superconductor. A high-quality single crystal sample of optimally doped Bi2212 ($\text{Pb} = 0.4$, $\text{Y} = 0.05$) was prepared by the Traveling Solvent Floating Zone (TSFZ) technique. Its orientation and crystallinity were confirmed via X-Ray Diffraction (XRD). The sample's electron transport and thermodynamic properties (electrical resistivity, magnetic susceptibility, and Seebeck coefficient) were measured over a wide temperature range from 5 to 300 K. Finally, ARPES measurements were performed to investigate the energy-momentum dispersion of conduction electrons in close vicinity to the Fermi energy. These measurements allowed us to study the evolution of the pseudogap and superconducting gap as a function of temperature and Fermi vector on the 2D Fermi surface. Ultimately, it is hoped that this work will lead to a better understanding of cuprate superconductivity in the optimally doped regime.

Investigation of Pseudogap in High- T_c Cuprate Superconductors – $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$



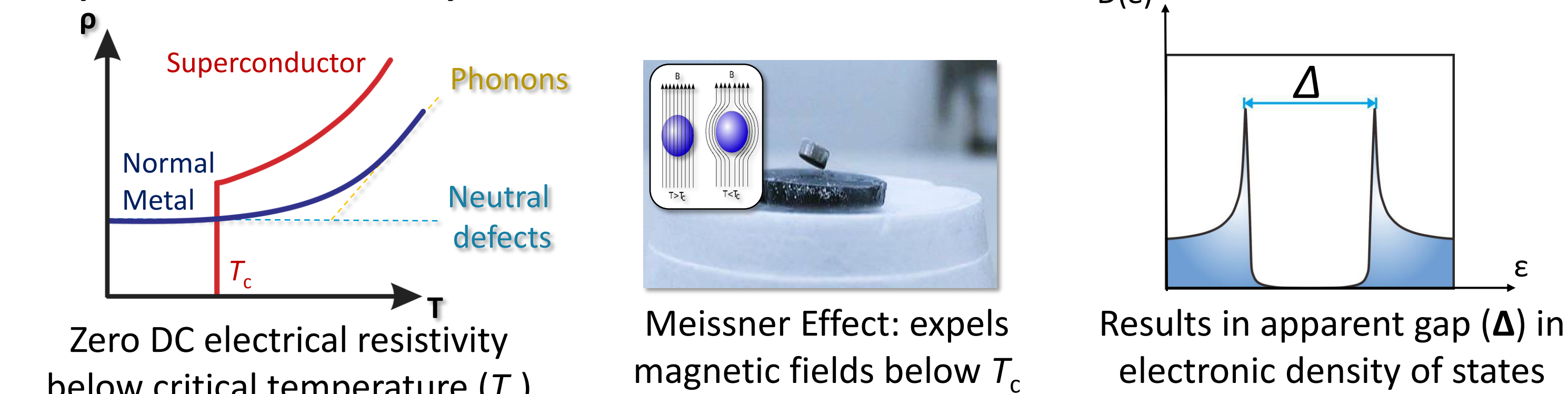
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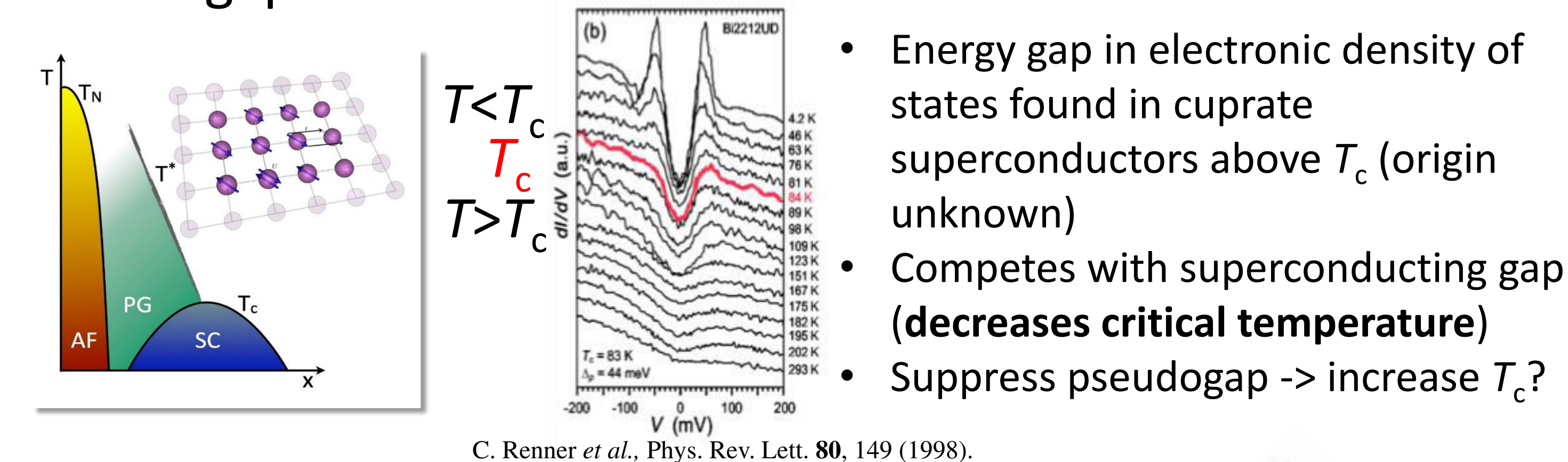
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Background and Purpose

Superconductivity:



Pseudogap:



Material— $\text{Bi}_2\text{Sr}_2\text{Ca}_1\text{Cu}_2\text{O}_{8+\delta}$ (Bi2212):

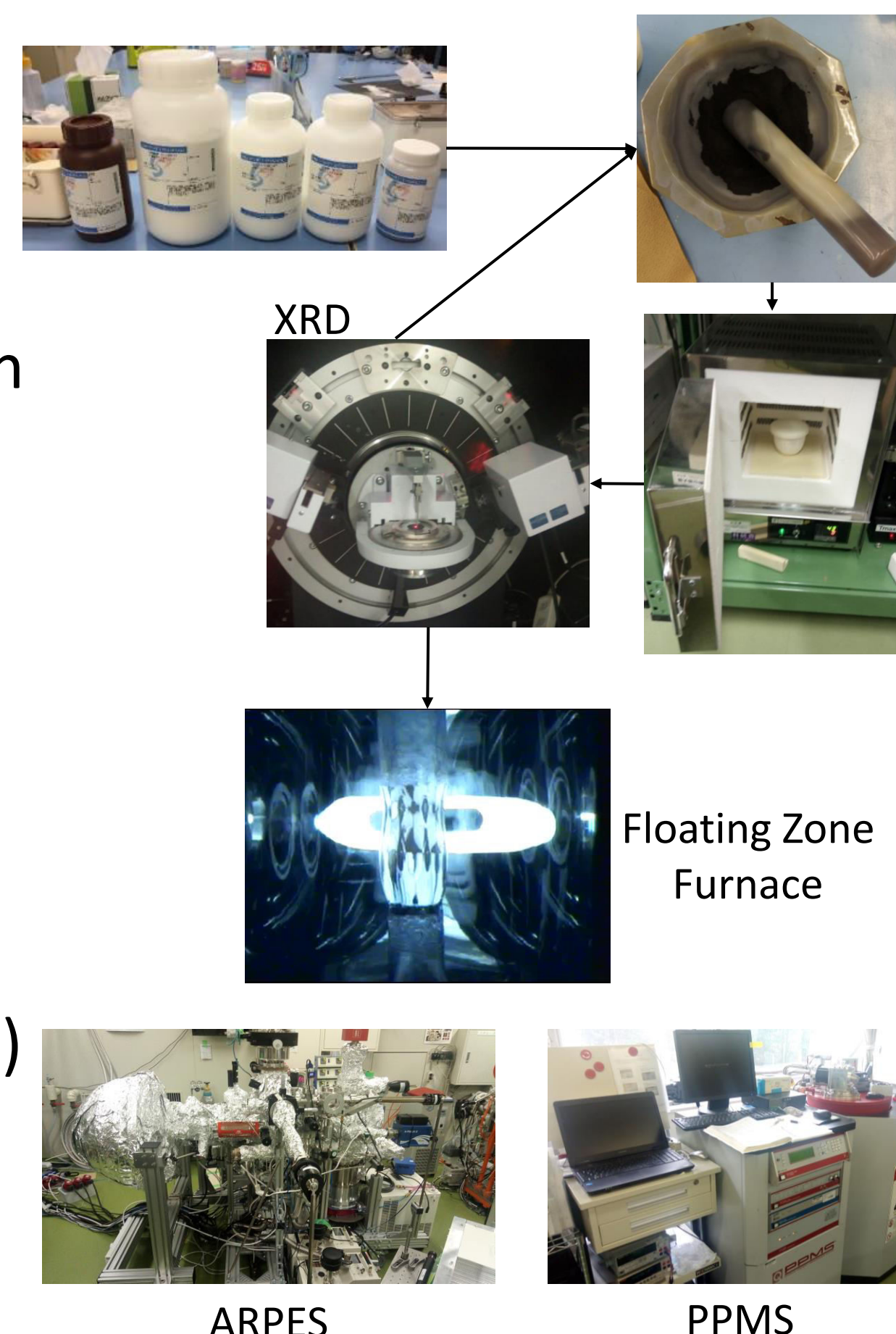
- High T_c Superconductor ($\sim 93\text{K}$)
- Doped with Pb and Y to control hole concentration (affects pseudogap)
- This sample: $(\text{Bi}_{1.7}\text{Pb}_{0.4})(\text{Ca}_{0.95}\text{Y}_{0.05})\text{Cu}_2\text{O}_{8+\delta}$ (optimally doped)

Purpose:

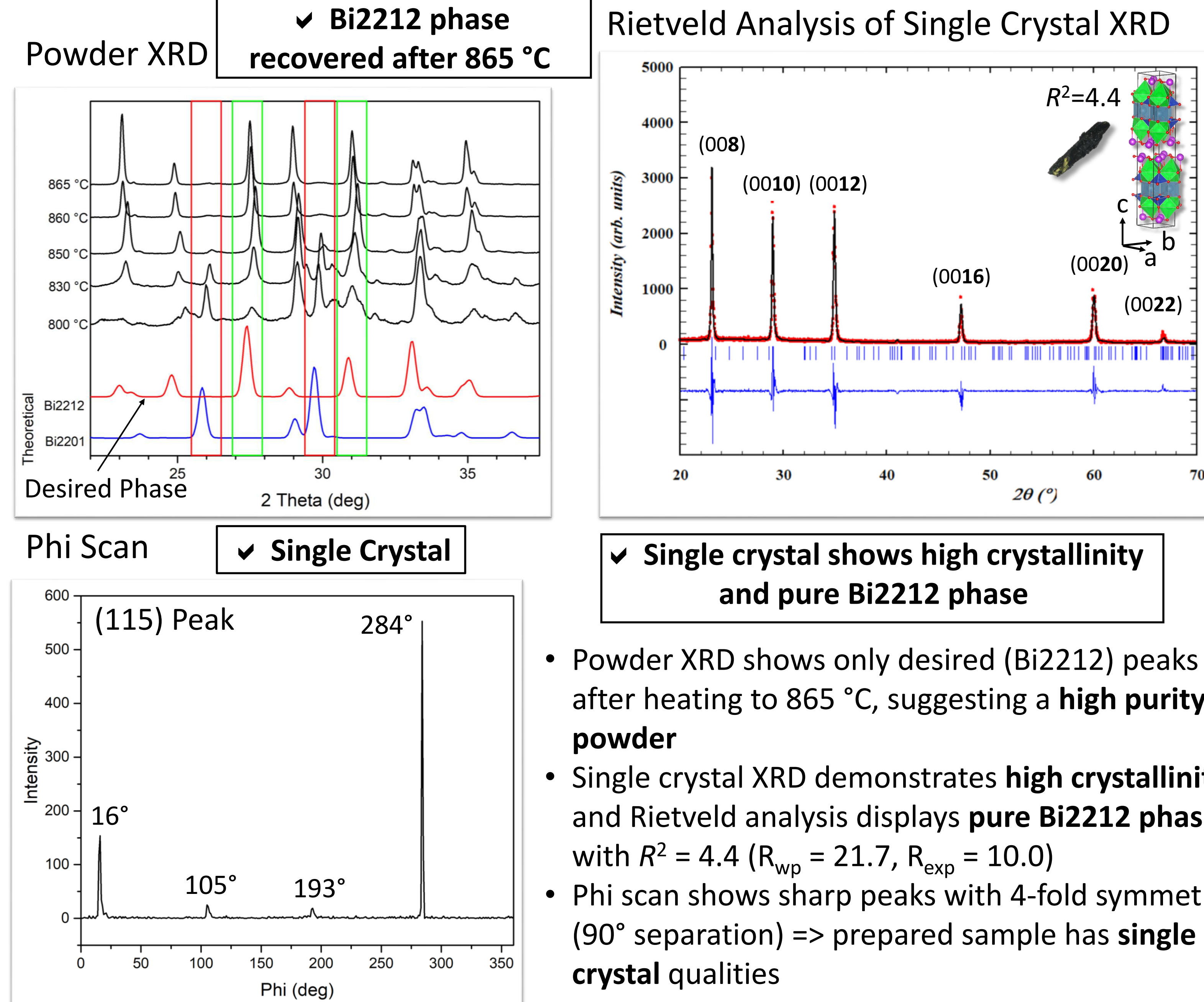
Characterize pseudogap and superconducting gap of Bi2212 sample in optimally-doped (max- T_c) regime in order to gain a better understanding of superconductivity in cuprates, with the hope of ultimately raising the T_c of these materials further

Experimental Procedure

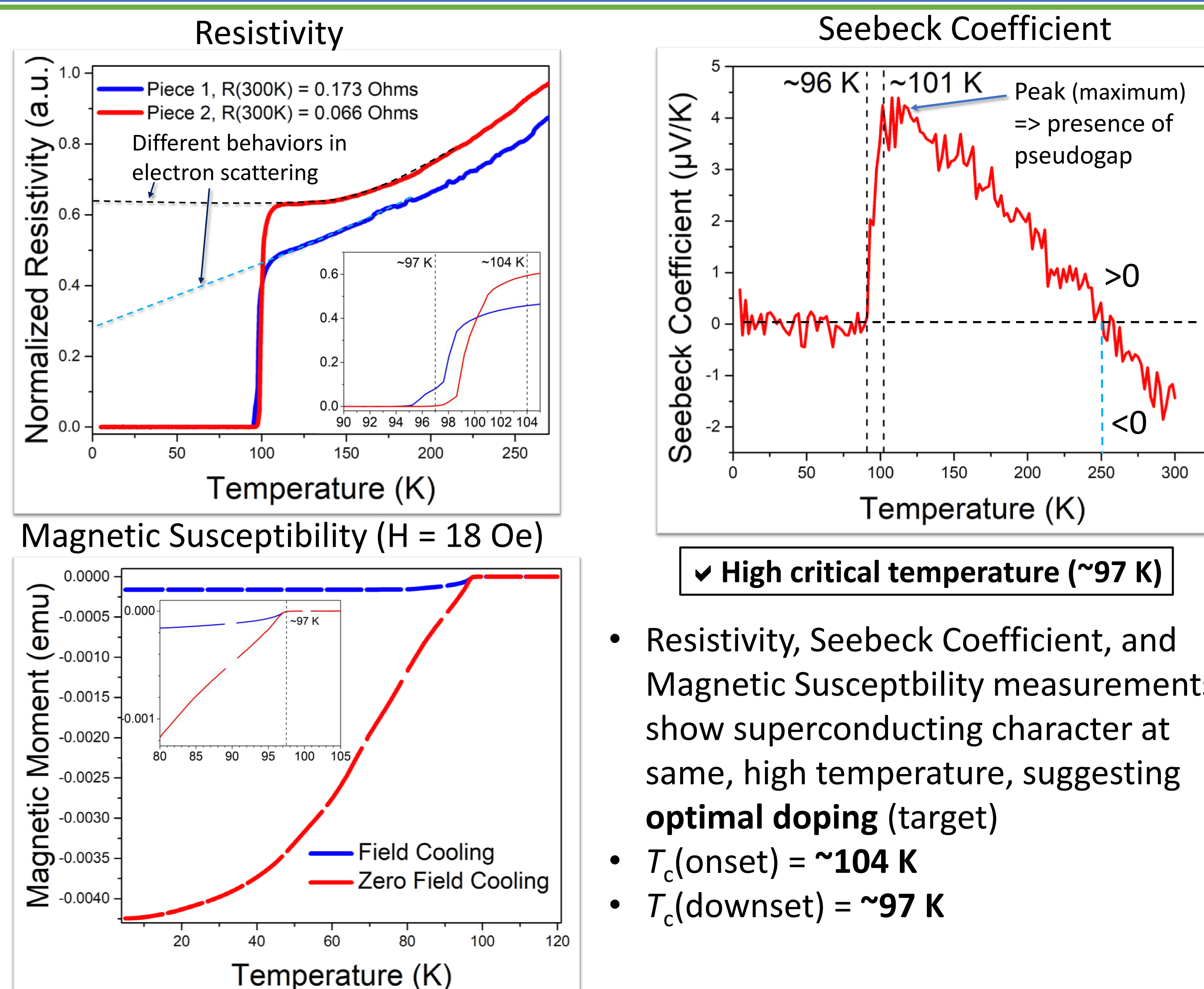
1. Dry, mix, and decarboxylate (700 °C, 24 hours) raw materials (Bi_2O_3 , PbO , SrCO_3 , CaCO_3 , Y_2O_3 , CuO)
2. Grind and heat for solid state reaction (72 hours)
3. Take XRD and check the present phases
4. If purity is not high enough, repeat 2 and 3 at a higher temperature
5. Grow single crystal in Traveling Solvent Floating Zone Furnace (TSFZF)
6. Analyze sample with XRD, PPMS, and ARPES



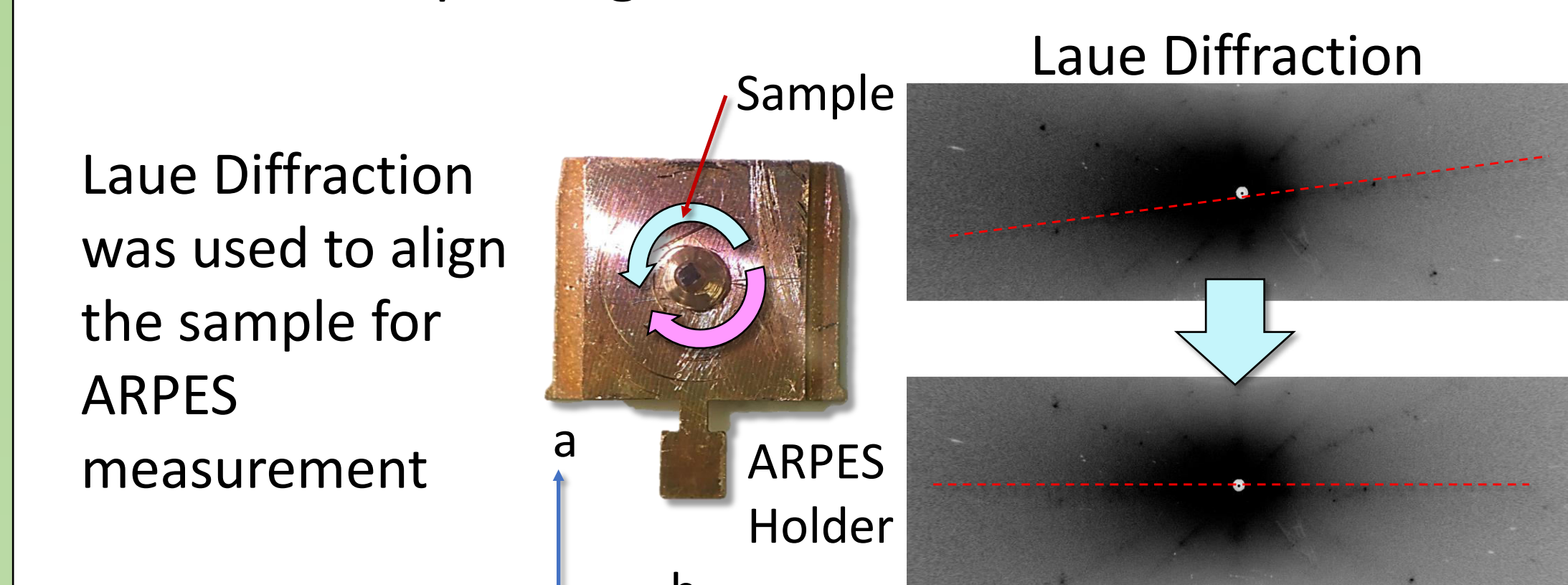
Results and Discussion



- Powder XRD shows only desired (Bi2212) peaks after heating to 865 °C, suggesting a **high purity powder**
- Single crystal XRD demonstrates **high crystallinity** and Rietveld analysis displays **pure Bi2212 phase**, with $R^2 = 4.4$ ($R_{wp} = 21.7$, $R_{exp} = 10.0$)
- Phi scan shows sharp peaks with 4-fold symmetry (90° separation) \Rightarrow prepared sample has **single crystal** qualities

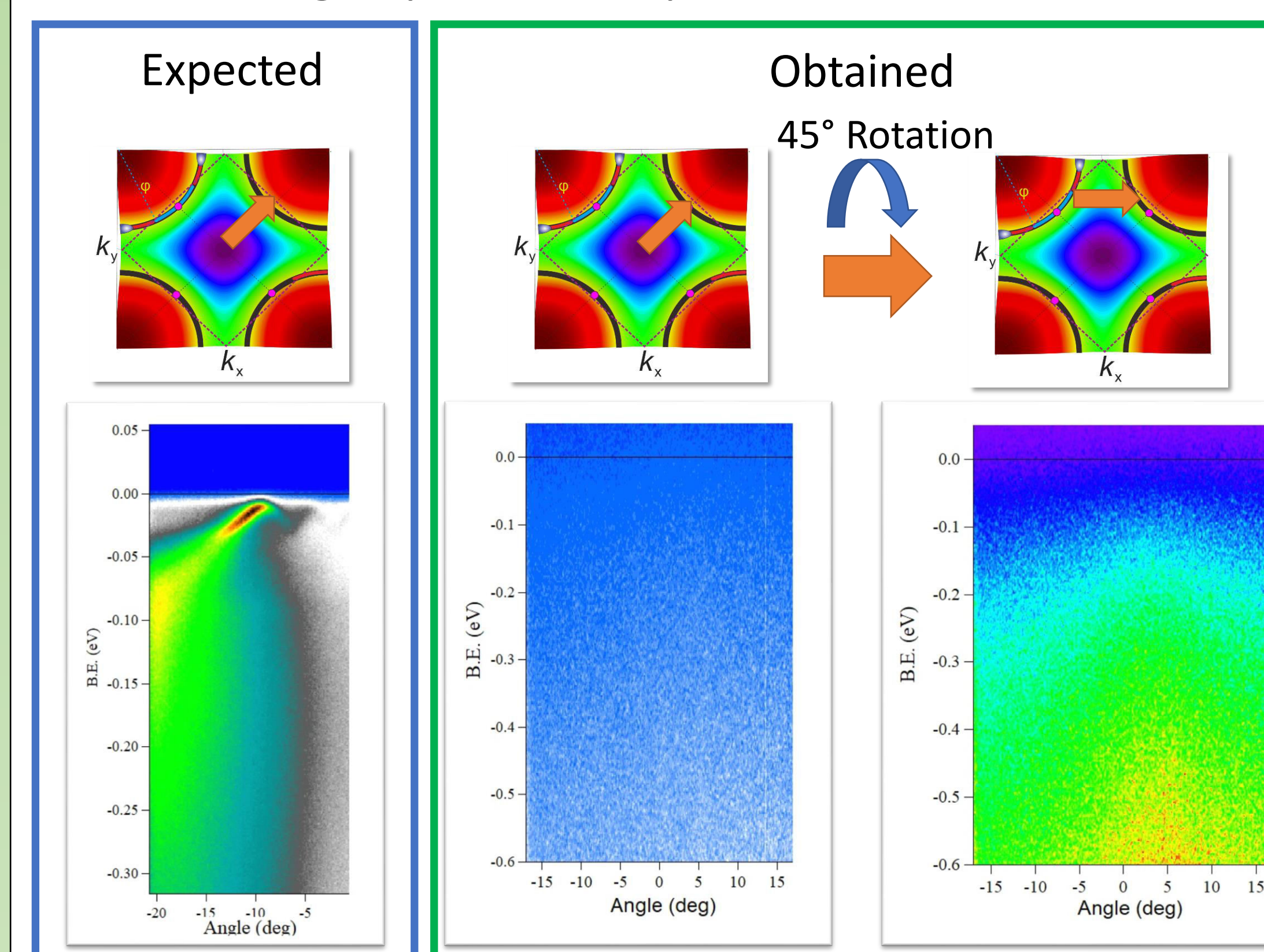


ARPES – Sample Alignment:



ARPES – Measurement

(Xe discharged plasma lamp, 8.47 eV):



- Unfortunately, **no dispersion pattern** observed (300 K)
- Reason unknown

Conclusions

- A high-quality single crystal sample of Bi2212 in the optimally-doped regime was successfully obtained
- An energy-momentum dispersion pattern was unable to be identified using ARPES for unknown reasons

Future Work

- Look for dispersion pattern in current sample or samples with the same doping condition
- Study samples with different doping conditions
- Use ARPES to learn about the relationship between hole concentration and pseudogap characteristics
- Vary parameters to possibly suppress pseudogap

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